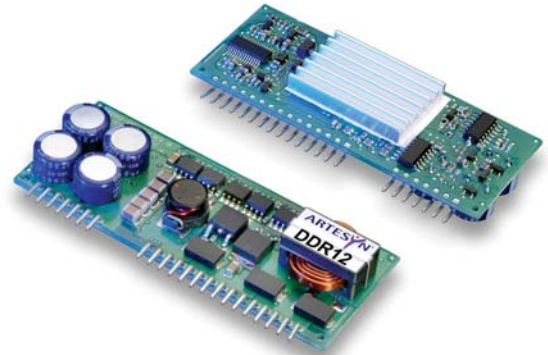


# DDR12 Series

## Dual output

**NEW Product**

- High current dual-output power module for DDR memory
- Single compact module provides 25A@2.5V for  $V_{ddq}$  supply and 8A@1.25V for  $V_{tt}$  termination
- Tracking dual output voltages (1.25V @ 8A, 2.5V @ 25A)
- Output voltage remote sense (only on  $V_{ddq}$ )
- Sink capability for logic terminations
- Power good output signal
- Over-voltage protection
- Over-current protection
- Remote ON/OFF



The dual output DDR12-25D08-A is specially designed to meet the power needs of double data rate memory DIMMS and associated memory control logic. The  $V_{tt}$  output tracks the  $V_{ddq}$  output, while the  $V_{tt}$  output can sink current as required by logic terminations. This converter offers typical efficiencies greater than 84% when operated at 50% load or greater. This model features a wide input range as well as trimmable output voltages. Remote sense on  $V_{ddq}$  and remote ON/OFF facilities are included as standard, and the converter is protected against over-current and over-voltage conditions.

**2 YEAR WARRANTY**

All specifications are typical at nominal input, full load at 25°C unless otherwise stated

### SPECIFICATIONS

#### OUTPUT SPECIFICATIONS - $V_{ddq}$

Voltage adjustability		2.32V to 2.75V
Output setpoint accuracy	Using 1% trim resistors	±2.5%
Line regulation	Low line to high line	±0.1%
Load regulation	Minimum load to full load	+0%/-1.0%
Cross regulation		±0.4%
Temperature Co-efficient		0.2mV/°C
Ripple and noise	5Hz to 20MHz	50mV pk-pk (See Note 1)
Transient response	4A/100µs	±3.0% deviation (See Note 2)
Overshoot	Nominal output at turn-on	2.0% max.
Undershoot		150mV max.

#### OUTPUT SPECIFICATIONS - $V_{tt}$

Tracking Accuracy	Measured at Converter Pins (= $V_{ddq}/2 - V_{tt}$ )	12mV
Ripple and noise	5Hz to 20MHz	30mV pk-pk (See Note 1)
Transient response	8A/1µs	±3.0% deviation (See Note 2)

#### INPUT SPECIFICATIONS

Input voltage range	Nominal 12V	10.8 to 13.2VDC
Input current	Minimum load Remote OFF	400mA 20mA
Input current (max.)	(See Note 3)	9A max. @ $I_o$ max. and $V_{in} = 10.8V$

#### INPUT SPECIFICATIONS - Contd.

Input reflected ripple	(See Note 4)	100mA (pk-pk)
Remote ON/OFF		
Logic compatibility	Open collector ref to -input	
ON		>2.0VDC
OFF		<0.8VDC
Start-up time	Power up	<20ms
(See Note 5)	Remote ON/OFF	<20ms

#### EMC CHARACTERISTICS

Electrostatic discharge	EN61000-4-2, IEC801-2
Conducted immunity	EN61000-4-2

#### GENERAL SPECIFICATIONS

Efficiency	$V_{ddq} = 2.5V$ $V_{tt} = 1.25V$	84% @ full load
Switching frequency	$V_{ddq}$ $V_{tt}$	300kHz typ. 300kHz typ.
Approvals and standards	(See Note 7)	Designed to EN60950
Material flammability		UL94V-0
Weight		34g (1.3oz)
MTBF	Telcordia SR-332	TBD hours

#### ENVIRONMENTAL SPECIFICATIONS

Thermal performance	Operating ambient, temperature	0°C to +80°C
	Non-operating	-40°C to +125°C

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OUTPUT POWER (MAX.)	INPUT VOLTAGE	OVP	OUTPUT VOLTAGE	OUTPUT CURRENT (MIN.)	OUTPUT CURRENT (MAX)	EFFICIENCY (TYP.)	LOAD REGULATION	MODEL NUMBER
69W	10.8-13.2VDC	3.6VDC	2.32-2.75V	1.5A	25A	84%	±1.0%	DDR12-25D08-A
11W		1.8VDC	1.16-1.375V	0A	8A		See Tracking Spec.	

### Notes

- 1 Measured as per recommended set-up.  $C_{in} = 270\mu\text{F}$  (20mΩ ESR max,  $C_{out} = 3 \times 560\mu\text{F}$  (5mΩ ESR max).
- 2  $V_{in} = 12\text{VDC}$ ,  $T_c = 25^\circ\text{C}$ , bounded by min/max load specification with recommended system caps.
- 3 External input fusing is recommended.
- 4 Measured with external filter.
- 5 Start-up into resistive load.
- 6 Meets levels A and B conducted emissions with external components.
- 7 This product is only for inclusion by professional installers within other equipment and must not be operated as a stand alone product.
- 8 Large value ceramic capacitor located close to the input pins is recommended (TDK p/N C4532X7R1E106M).
- 9 Use of additional high quality ceramic output capacitors is recommended in the end system.

### PROTECTION

Short-circuit protection	$V_{ddq}$ $V_{tt}$	Latching Latching
Over-voltage protection	$V_{ddq}$ $V_{tt}$	Latching Latching
Over-current protection	$V_{ddq}$ $V_{tt}$	Latching Fold-back

### RECOMMENDED SYSTEM CAPACITANCE

Input capacitance	(See Note 8)	10μF/3mΩ ESR max.
Output capacitance (See Note 9)	$V_{ddq}$ $V_{tt}$	1680μF/5mΩ ESR max. 1680μF/5mΩ ESR max.

**CAUTION: Hazardous internal voltages and high temperatures. Ensure that unit is not user accessible.**

### PIN CONNECTIONS

PIN NO.	FUNCTION	PIN NO.	FUNCTION
J1-1	Power Good	J2-5	Ground
J1-2	Output Enable	J2-6	Ground
J1-3	Ground	J2-7	Ground
J1-4	Ground	J2-8	Ground
J1-5	12V Input	J2-9	$V_{ddq}$ Sense -
J1-6	12V Input	J2-10	$V_{ddq}$ Sense +
J1-7	12V Input	J2-11	$V_{ddq}$
J2-1	$V_{tt}$ Ref	J2-12	$V_{ddq}$
J2-2	$V_{tt}$	J2-13	$V_{ddq}$
J2-3	$V_{tt}$	J2-14	$V_{ddq}$
J2-4	Ground	J2-15	$V_{ddq}$

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